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PART OBSOLETE – USE BC847BLP4

Lead-free Green

DN0150ALP4 / DN0150BLP4

50V NPN SMALL SIGNAL TRANSISTOR IN DFN1006

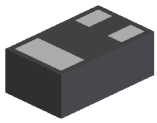
Features

- BV_{CEO} > 50V
- I_C = 100mA High Collector Current
- P_D = 1000mW Power Dissipation
- 0.60mm^2 Package Footprint, 13 times Smaller than SOT23
- 0.4mm Height Package Minimizing Off-Board Profile
- Complementary PNP Type: DP0150ALP4/DP0150BLP4
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

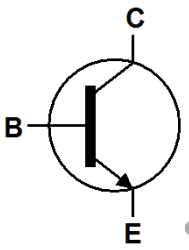
Mechanical Data

- Case: X2-DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish — NiPdAu. Solderable per MIL-STD-202, Method 208 e4
- Weight: 0.0008 grams (Approximate)

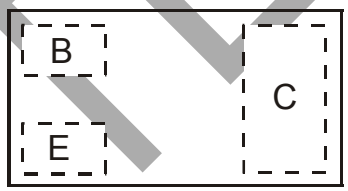
X2-DFN1006-3



Bottom View



Device Symbol



Top View
Pin Configuration

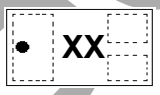
Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DN0150ALP4-7	T3	7	8	3,000
DN0150ALP4-7B	T3	7	8	10,000
DN0150BLP4-7	T4	7	8	3,000
DN0150BLP4-7B	T4	7	8	10,000

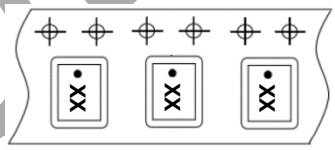
Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

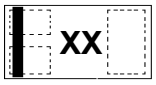
DN0150ALP4-7
DN0150BLP4-7



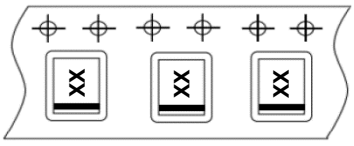
Top View
Dot Denotes Collector Side



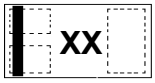
From date code 1527 (YYWW), this changes to:



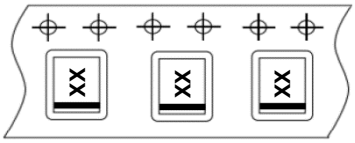
Top View
Bar Denotes Base and Emitter Side



DN0150ALP4-7B
DN0150BLP4-7B



Top View
Bar Denotes Base and Emitter Side



XX = Product Type Marking Code
(See Ordering Information)

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Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	60	V
Collector-Emitter Voltage	V_{CEO}	50	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current – Continuous	I_C	100	mA
Peak Pulse Collector Current	I_{CM}	200	mA
Base Current	I_B	30	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	P_D	400	mW
	(Note 6)		1000	
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	310	°C/W
	(Note 6)		120	
Thermal Resistance, Junction to Lead	(Note 7)	$R_{\theta JL}$	120	°C/W
Operating and Storage and Temperature Range		T_J, T_{STG}	-55 to +150	°C

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS							
Collector-Base Breakdown Voltage		BV_{CBO}	60	—	—	V	I_C = 10μA, I_E = 0
Collector-Emitter Breakdown Voltage (Note 8)		BV_{CEO}	50	—	—	V	I_C = 1mA, I_B = 0
Emitter-Base Breakdown Voltage		BV_{EBO}	5	—	—	V	I_E = 10μA, I_C = 0
Collector Cut-Off Current		I_{CBO}	—	—	0.1	μA	V_{CB} = 60V, I_E = 0
Emitter Cut-Off Current		I_{EBO}	—	—	0.1	μA	V_{EB} = 5V, I_C = 0
ON CHARACTERISTICS (Note 9)							
Collector-Emitter Saturation Voltage		$V_{CE(SAT)}$	—	0.10	0.25	V	I_C = 100mA, I_B = 10mA
DC Current Gain	DN0150ALP4	h_{FE}	120	—	240	—	V_{CE} = 6V, I_C = 2mA
	DN0150BLP4		200	—	400		
SMALL SIGNAL CHARACTERISTICS							
Transition Frequency		f_T	60	—	—	MHz	V_{CE} = 10V, I_E = -1mA f = 30MHz
Output Capacitance		C_{ob}	—	1.3	—	pF	V_{CB} = 10V, I_E = 0, f = 1MHz

Notes:
5. For the device mounted on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady state condition. The entire exposed collector pad is attached to the heatsink.
6. Same as Note 5, except the exposed collector pad is mounted on 25mm x 25mm 2oz copper.
7. Thermal resistance from junction to solder-point (on the exposed collector pad).
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.
9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

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Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

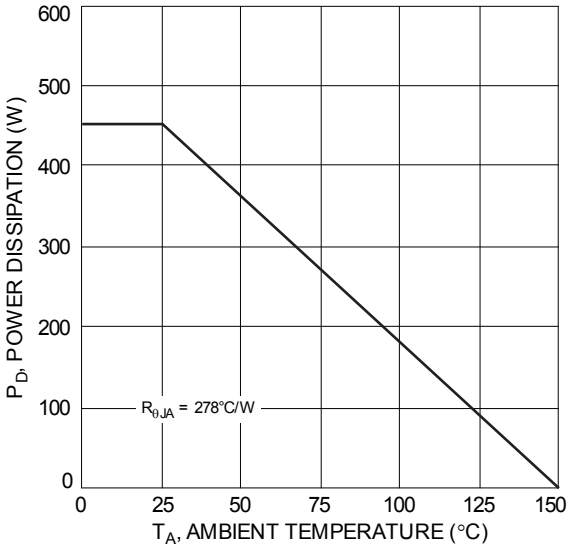

Fig. 1 Power Dissipation vs. Ambient Temperature (Note 3)

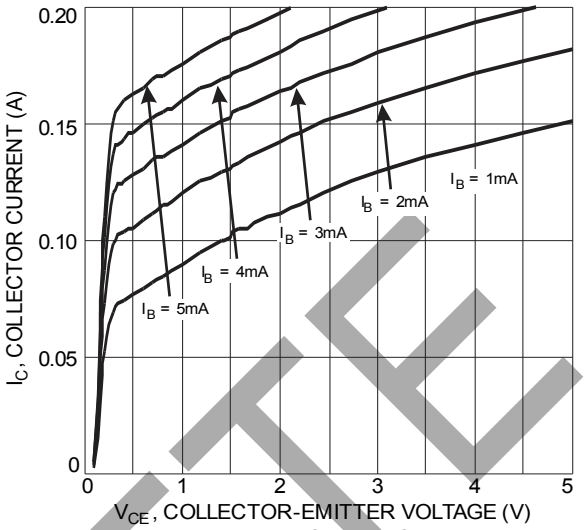

Fig. 2 Typical Collector Current vs. Collector-Emitter Voltage (DN0150BLP4)

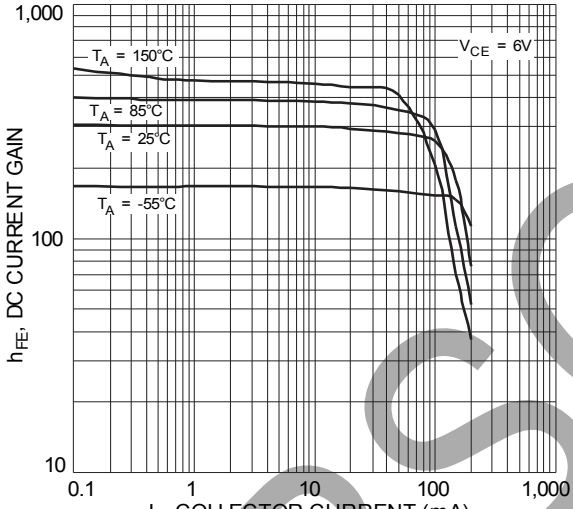

Fig. 3 Typical DC Current Gain vs. Collector Current (DN0150BLP4)

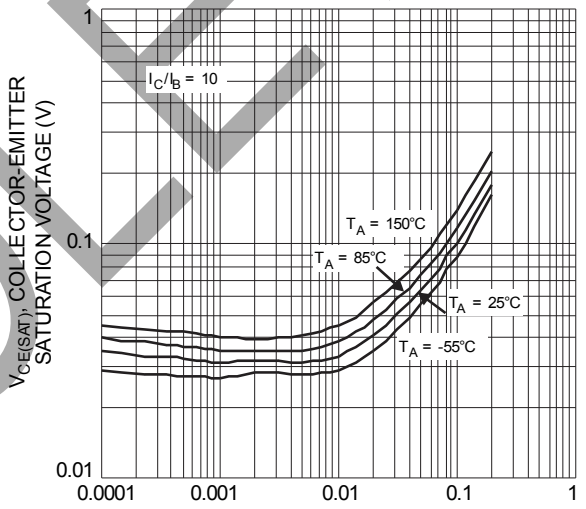

Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

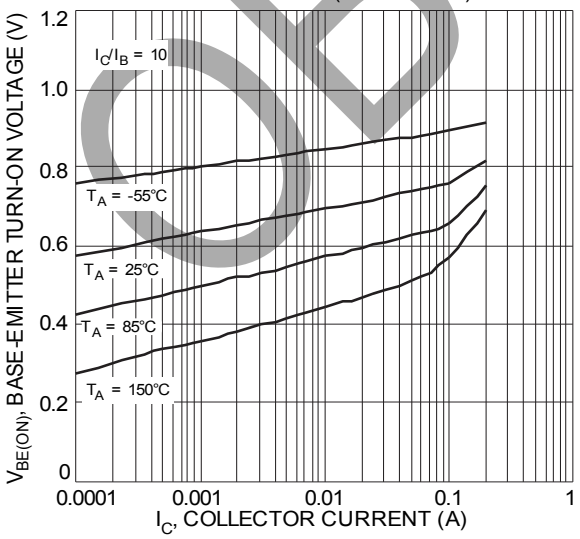

Fig. 5 Typical Base-Emitter Turn-On Voltage vs. Collector Current

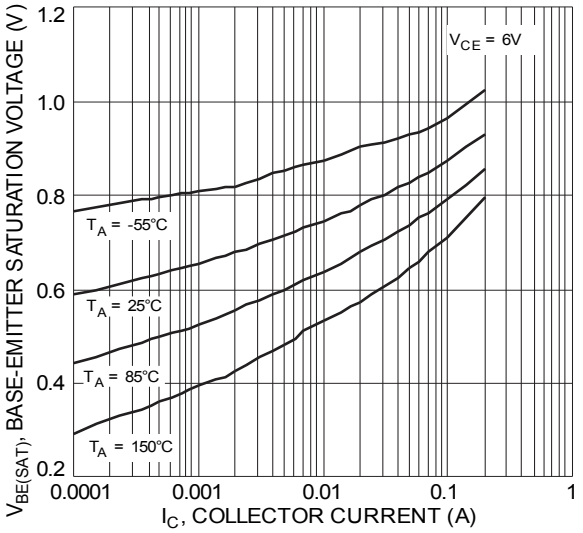

Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current

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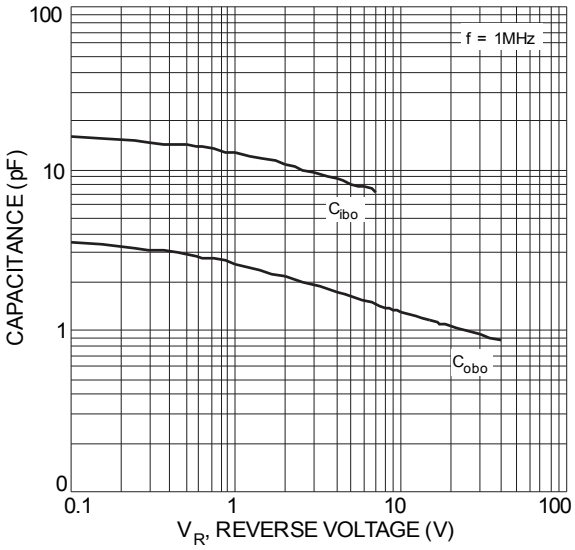


Fig. 7 Typical Capacitance Characteristics

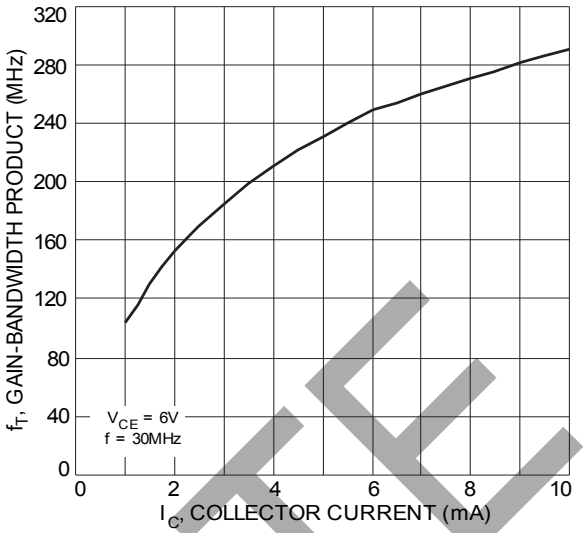
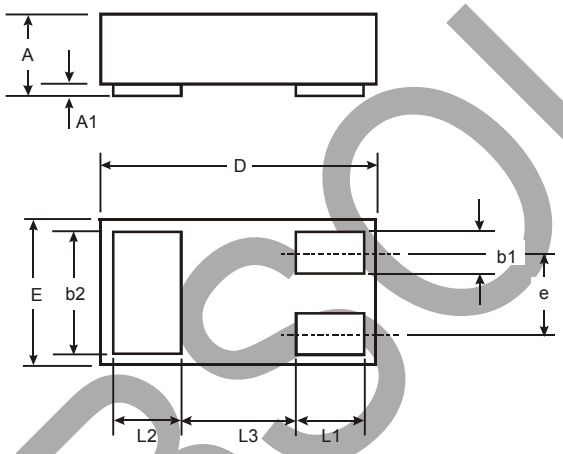


Fig. 8 Typical Gain-Bandwidth Product vs. Collector Current

Package Outline Dimensions

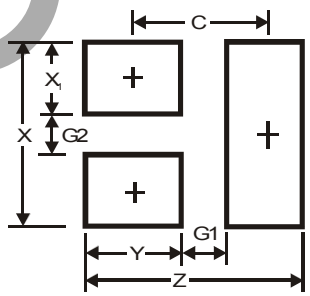
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



X2-DFN1006-3			
Dim	**Min**	**Max**	**Typ**
A	—	0.40	—
A1	0	0.05	0.02
b1	0.10	0.20	0.15
b2	0.45	0.55	0.50
D	0.95	1.05	1.00
E	0.55	0.65	0.60
e	—	—	0.35
L1	0.20	0.30	0.25
L2	0.20	0.30	0.25
L3	—	—	0.40
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	1.1
G1	0.3
G2	0.2
X	0.7
X1	0.25
Y	0.4
C	0.7

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